

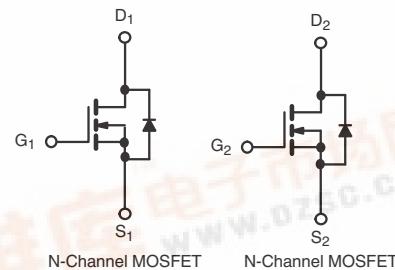
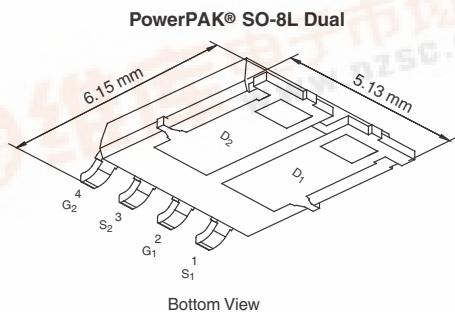
Automotive Dual N-Channel 75 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	75
$R_{DS(on)}$ (Ω) at $V_{GS} = 10$ V	0.050
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5$ V	0.070
I_D (A) per leg	8
Configuration	Dual

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 Qualified^d

AUTOMOTIVE GRADE


RoHS
 COMPLIANT
 HALOGEN
 FREE
**ORDERING INFORMATION**

Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ980EP-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	75	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^a	I_D	8	A
		8	
Continuous Source Current (Diode Conduction) ^a	I_S	8	
Pulsed Drain Current ^b	I_{DM}	32	
Single Pulse Avalanche Current	I_{AS}	18	mJ
Single Pulse Avalanche Energy	E_{AS}	16	
Maximum Power Dissipation ^b	P_D	34	W
		11	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to + 175	°C
Soldering Recommendations (Peak Temperature) ^{e, f}		260	

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-Ambient	R_{thJA}	85	°C/W
Junction-to-Case (Drain)	R_{thJC}	4.3	

Notes

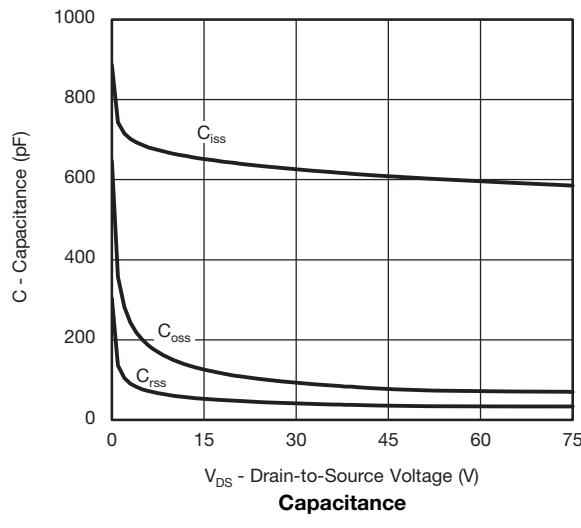
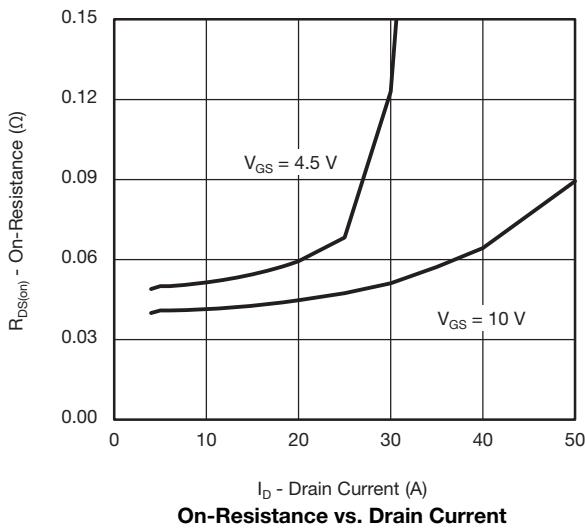
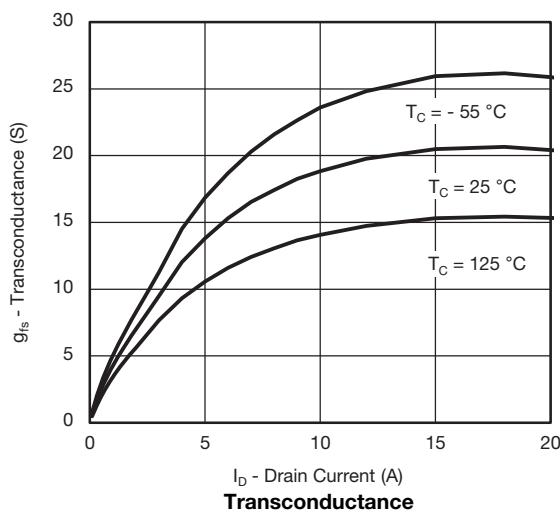
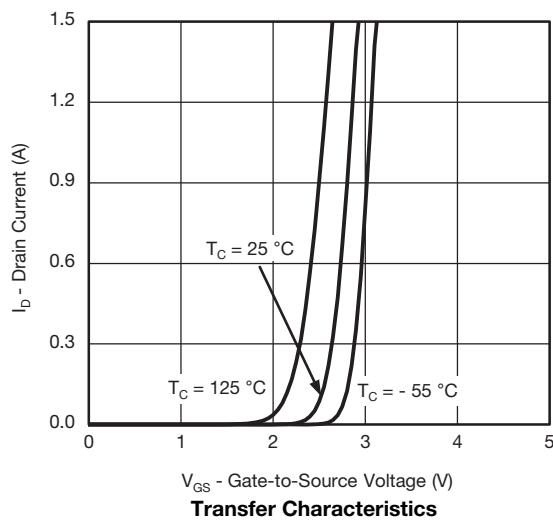
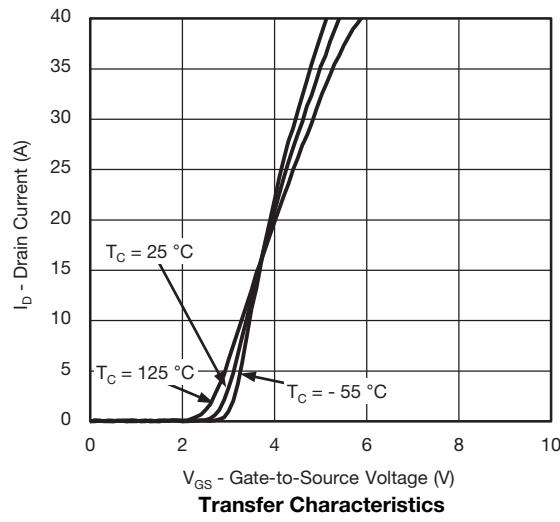
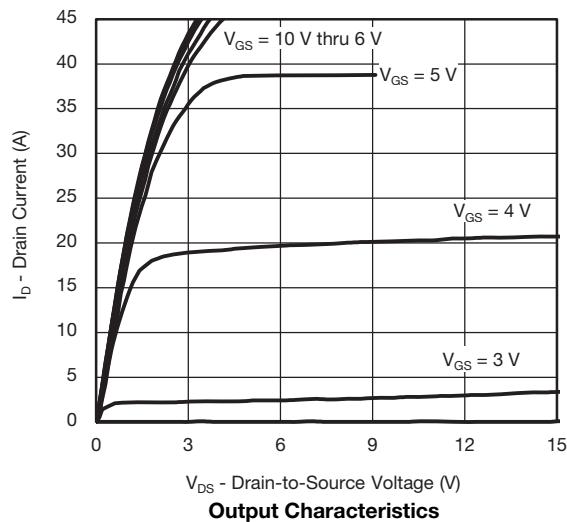
- Package limited.
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR4 material).
- Parametric verification ongoing.
- See solder profile (www.vishay.com/ppg?7257). The PowerPAK SO-8L. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection..
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

SPECIFICATIONS ($T_C = 25^\circ\text{C}$, unless otherwise noted)										
PARAMETER	SYMBOL	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT		
Static										
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}$, $I_D = 250 \mu\text{A}$			75	-	-	V		
Gate-Source Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu\text{A}$			1.5	2.0	2.5			
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 20 \text{ V}$			-	-	± 100	nA		
Zero Gate Voltage Drain Current	I_{DSS}	$V_{GS} = 0 \text{ V}$	$V_{DS} = 75 \text{ V}$		-	-	1	μA		
		$V_{GS} = 0 \text{ V}$	$V_{DS} = 75 \text{ V}$, $T_J = 125^\circ\text{C}$		-	-	50			
		$V_{GS} = 0 \text{ V}$	$V_{DS} = 75 \text{ V}$, $T_J = 175^\circ\text{C}$		-	-	150			
On-State Drain Current ^a	$I_{D(\text{on})}$	$V_{GS} = 10 \text{ V}$	$V_{DS} \geq 5 \text{ V}$		30	-	-	A		
Drain-Source On-State Resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = 10 \text{ V}$	$I_D = 5 \text{ A}$		-	0.041	0.050	Ω		
		$V_{GS} = 10 \text{ V}$	$I_D = 5 \text{ A}$, $T_J = 125^\circ\text{C}$		-	-	0.092			
		$V_{GS} = 10 \text{ V}$	$I_D = 5 \text{ A}$, $T_J = 175^\circ\text{C}$		-	-	0.119			
		$V_{GS} = 4.5 \text{ V}$	$I_D = 4.5 \text{ A}$		-	0.060	0.070			
Forward Transconductance ^b	g_{fs}	$V_{DS} = 15 \text{ V}$, $I_D = 4 \text{ A}$			-	12	-	S		
Dynamic^b										
Input Capacitance	C_{iss}	$V_{GS} = 0 \text{ V}$	$V_{DS} = 25 \text{ V}$, $f = 1 \text{ MHz}$	-	630	790	pF			
Output Capacitance	C_{oss}			-	100	125				
Reverse Transfer Capacitance	C_{rss}			-	44	55				
Total Gate Charge ^c	Q_g	$V_{GS} = 10 \text{ V}$	$V_{DS} = 35 \text{ V}$, $I_D = 9.7 \text{ A}$	-	14	21	nC			
Gate-Source Charge ^c	Q_{gs}			-	2.3	-				
Gate-Drain Charge ^c	Q_{gd}			-	3.0	-				
Turn-On Delay Time ^c	$t_{d(\text{on})}$	$V_{DD} = 35 \text{ V}$, $R_L = 35 \Omega$ $I_D \geq 1 \text{ A}$, $V_{GEN} = 10 \text{ V}$, $R_g = 1 \Omega$			-	8	12	ns		
Rise Time ^c	t_r				-	9	14			
Turn-Off Delay Time ^c	$t_{d(\text{off})}$				-	19	29			
Fall Time ^c	t_f				-	8	12			
Source-Drain Diode Ratings and Characteristics^b										
Pulsed Current ^a	I_{SM}				-	-	32	A		
Forward Voltage	V_{SD}	$I_F = 4 \text{ A}$, $V_{GS} = 0 \text{ V}$			-	0.8	1.1	V		

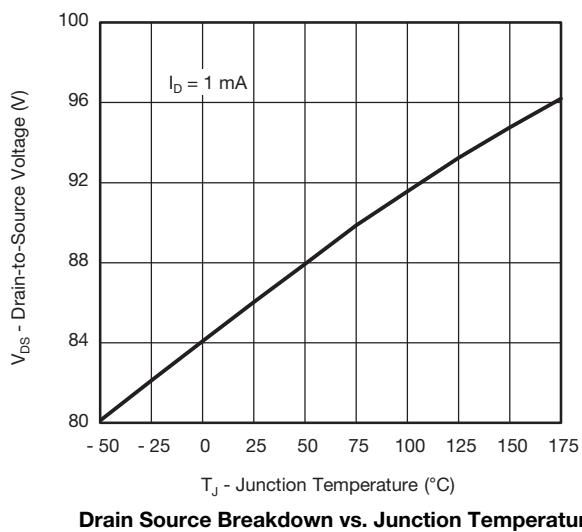
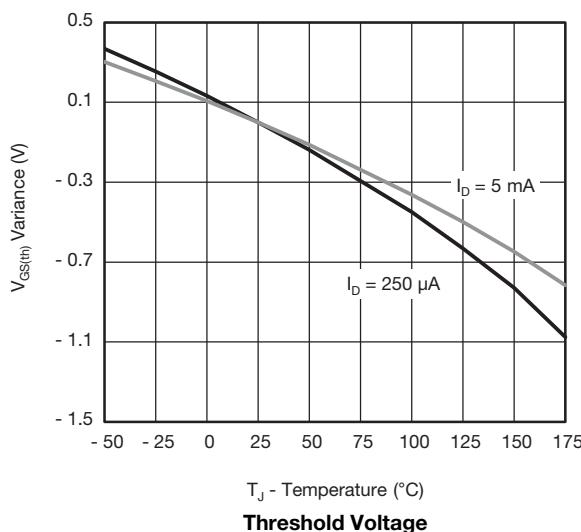
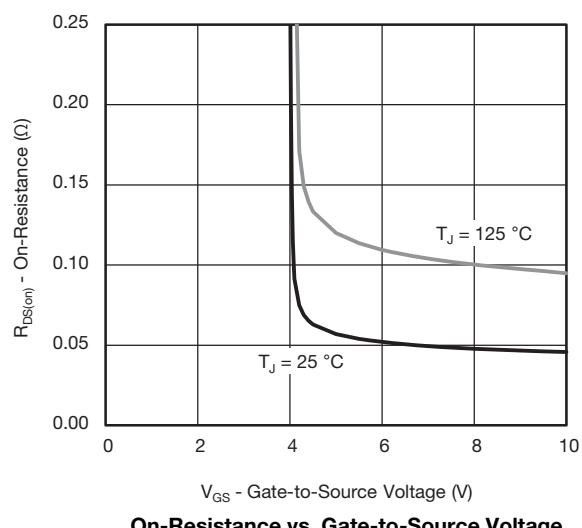
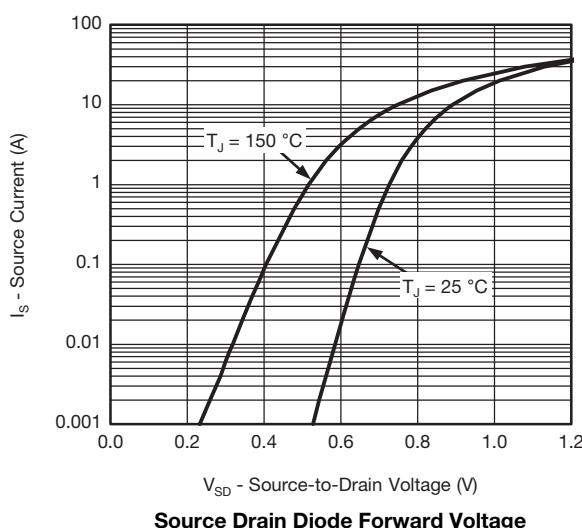
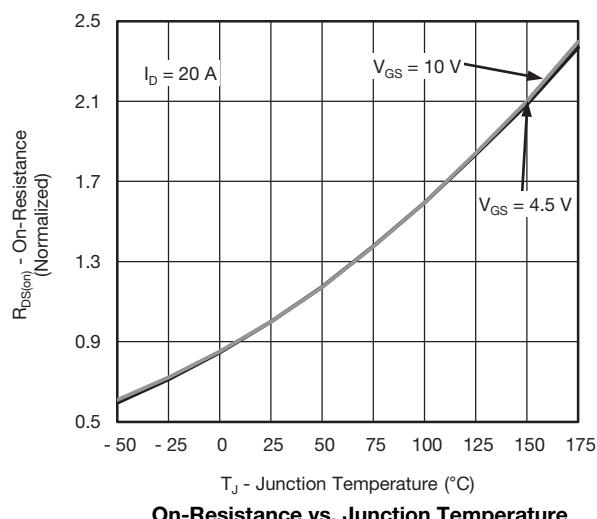
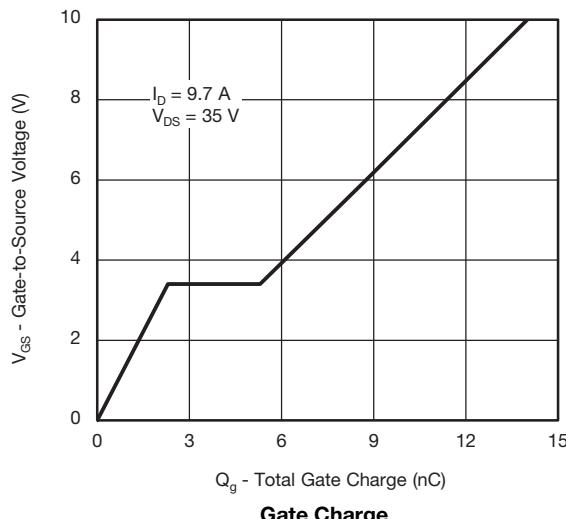
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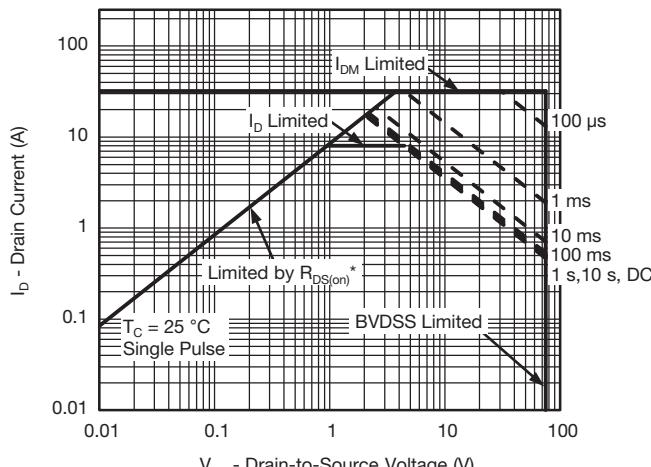
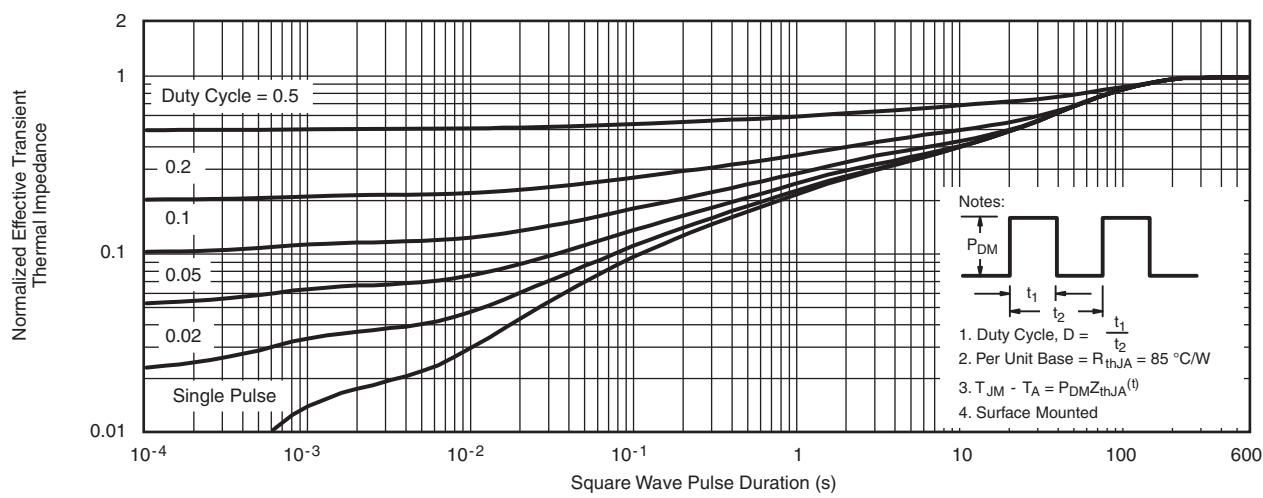
- a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

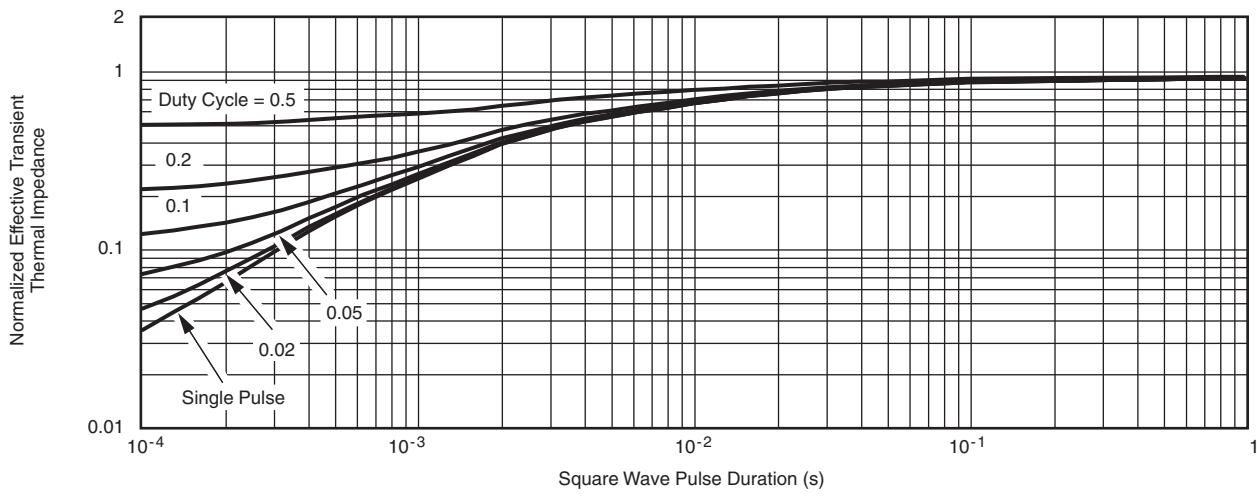
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)


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THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)**Safe Operating Area****Normalized Thermal Transient Impedance, Junction-to-Ambient**

THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)**Normalized Thermal Transient Impedance, Junction-to-Case****Note**

- The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25°C)
- Normalized Transient Thermal Impedance Junction-to-Case (25°C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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